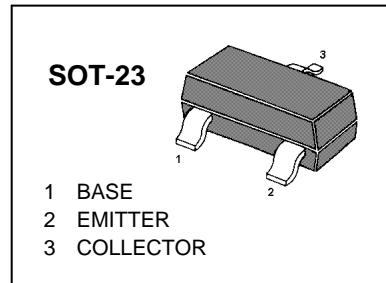


FEATURES

Complementary to S9015

MARKING: J6

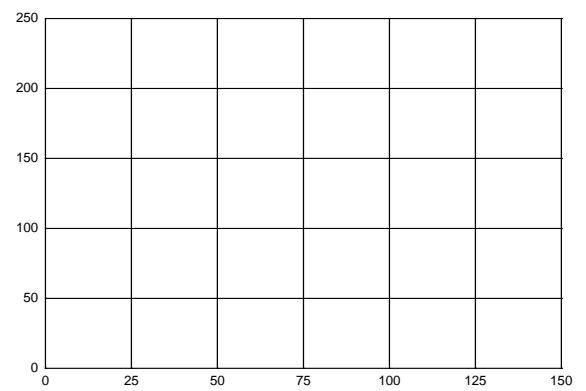
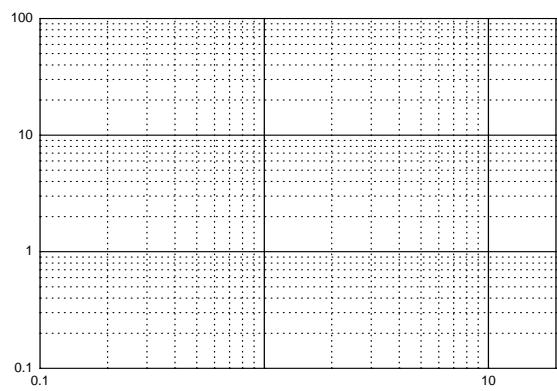
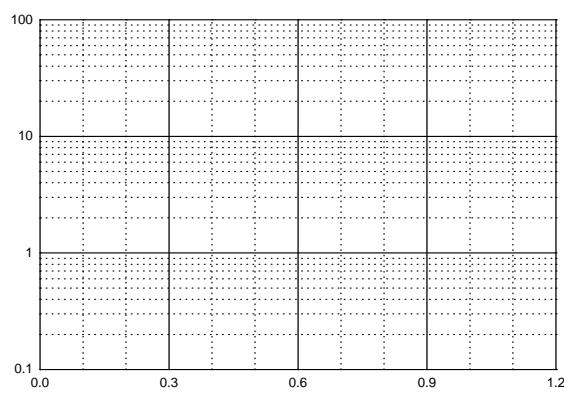
MAXIMUM RATINGS ($T_A=25^\circ\text{C}$ unless otherwise noted)

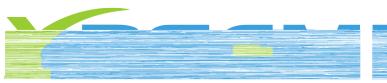
Symbol	Parameter	value	units
V_{CBO}	Collector-Base Voltage	50	V
V_{CEO}	Collector-Emitter Voltage	45	V
V_{EBO}	Emitter-Base Voltage	5	V
I_C	Collector Current-Continuous	0.1	A
P_c	Collector Power Dissipation	0.2	W
T_J	Junction Temperature	150	
T_{STG}	Storage Temperature	-55-150	

ELECTRICAL CHARACTERISTICS (Tamb=25°C unless otherwise specified)

Parameter	Symbol	Test conditions	MIN	TYP	MAX	UNIT
Collector-base breakdown voltage	$V_{(BR)CBO}$	$I_C= 100\mu\text{A}, I_E=0$	50			V
Collector-emitter breakdown voltage	$V_{(BR)CEO}$	$I_C= 0.1\text{mA}, I_B=0$	45			V
Emitter-base breakdown voltage	$V_{(BR)EBO}$	$I_E=100\mu\text{A}, I_C=0$	5			V
Collector cut-off current	I_{CBO}	$V_{CB}=50\text{V}, I_E=0$		0.1		μA
Collector cut-off current	I_{CEO}	$V_{CE}=35\text{V}, I_B=0$		0.1		μA
Emitter cut-off current	I_{EBO}	$V_{EB}= 3\text{V}, I_C=0$		0.1		μA
DC current gain	h_{FE}	$V_{CE}=5\text{V}, I_C= 1\text{mA}$	200		450	
Collector-emitter saturation voltage	$V_{CE}(\text{sat})$	$I_C=100 \text{ mA}, I_B= 5\text{mA}$		0.3		V
Base-emitter saturation voltage	$V_{BE}(\text{sat})$	$I_C=100 \text{ mA}, I_B= 5\text{mA}$		1		V
Transition frequency	f_T	$V_{CE}=5\text{V}, I_C= 10\text{mA}$ $f=30\text{MHz}$	150			MHz

Typical Characteristics

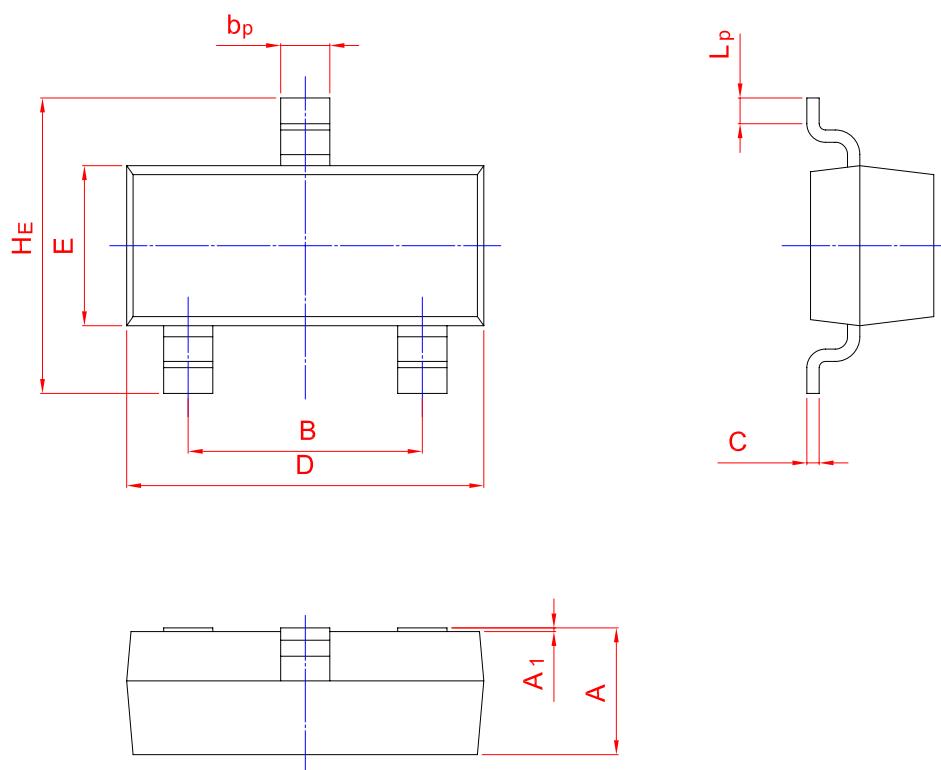




PACKAGE OUTLINE

Plastic surface mounted package; 3 leads

SOT-23



UNIT	A	B	b _p	C	D	E	H _E	A ₁	L _p
mm	1.40 0.95	2.04 1.78	0.50 0.35	0.19 0.08	3.10 2.70	1.65 1.20	3.00 2.20	0.100 0.013	0.50 0.20